

IAP20 Rec'd 17 DEC 20 22 DEC 2005  
APPLICATION DATA SHEET

## APPLICATION INFORMATION

Application Number::  
Filing Date:: December 22, 2005  
Application type:: Regular  
Subject Matter:: Utility  
Title:: High-Heat-Resistant Semiconductor  
Device  
Attorney Docket No.: 102253.57240US  
Request for Early Publication?: No  
Request for Non-Publication?: No  
Suggested Drawing Figure:: 1  
Total Drawing Sheets:: 6  
Small Entity?: No  
Petition included?: No

## APPLICANT INFORMATION

Applicant one Authority Type::	Inventor
Primary Citizenship Country::	Japan
Status::	Full Capacity
Given name::	Yoshitaka
Family name::	SUGAWARA
Residence	Osaka, Japan
Street of mailing address::	c/o The Kansai Electric Power Co., Inc. 6-16, Nakanoshima 3-chome, Kita-ku,
City of mailing address::	Osaka-shi
State or Province of mailing address::	Osaka
Country of mailing address::	Japan
Postal or Zip Code of mailing address::	530-8270

## CORRESPONDENCE INFORMATION

Correspondence customer number:: 23911

## REPRESENTATIVE INFORMATION

Representative customer number:: 23911

## DOMESTIC PRIORITY INFORMATION

Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This application	is a 371 National Stage of	PCT/JP2004/010315	07/20/2004

## FOREIGN PRIORITY INFORMATION

Country::	Application Number::	Filing Date::	Priority Claimed::
JP	2003-283057	07/30/2003	Yes

## ASSIGNEE INFORMATION

Assignee Name:: The Kansai Electric Power Co., Inc.  
Street of mailing address:: 6-16, Nakanoshima 3-chome, Kita-ku,  
City of mailing address:: Osaka-shi,  
State or Province of Mailing Address:: Osaka  
Country of Mailing Address:: Japan  
Postal or Zip Code of mailing address:: 530-8270